

Features

100W (8x20us) Peak Pulse Power

Low Clamping Voltage

SOD-523 Package

RoHS Compliant

Matte Tin Lead finish (Pb-Free)

Protect One I/O or Power Line

Meet IEC61000-4-2 Level 4:

Contact Discharge >30kV

Air Discharge >30kV

Applications

Smart Phones

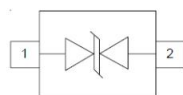
Laptop Computers

Portable Electronics

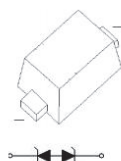
Circuit Diagram

Pin 1  Pin 2

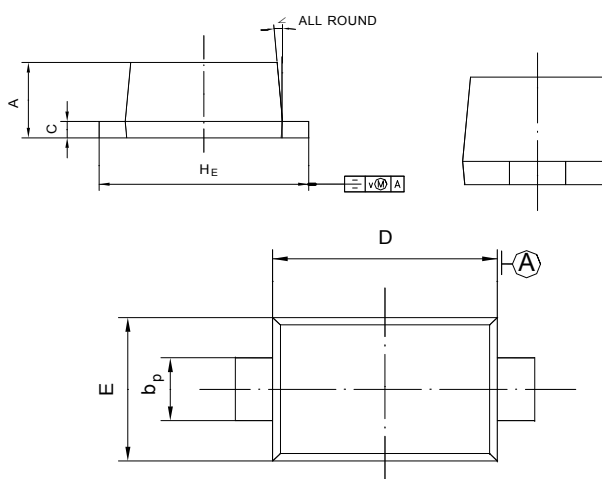
PIN Diagram



SOD-523



SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.70 0.50	0.40 0.20	0.14 0.05	1.30 1.10	0.90 0.75	1.70 1.50	0.1	5°

Dimensions in inches and (millimeters)

Maximum Ratings (Ta = 25°C)

Symbol	Parameter	Value	Unit
TJ	Junction Temperature	-55 to +150	°C
TSTG	Storage Temperature	-55 to +150	°C
Ipp Max	Maximum Peak Pulse Current	7	A
PPK	Peak Pulse Power	100	W

CESDBLC5V0D5

- (1).Device stressed with ten non-repetitive ESD pulses.
- (2).Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5.

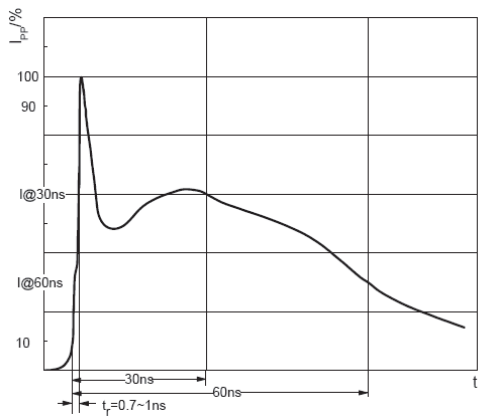
ESD standards compliance

IEC61000-4-2 Standard

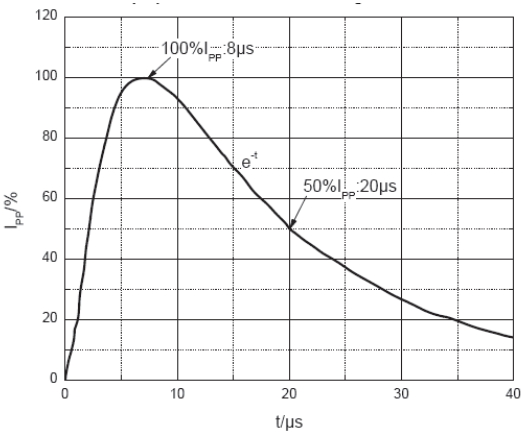
Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999



ESD pulse waveform according to IEC61000-4-2

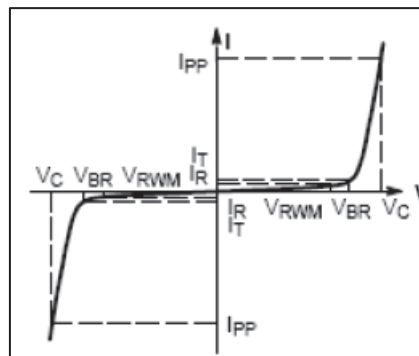


8/20μs pulse waveform according to IEC 61000-4-5

CESDBLC5V0D5

ELECTRICAL PARAMETER

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage

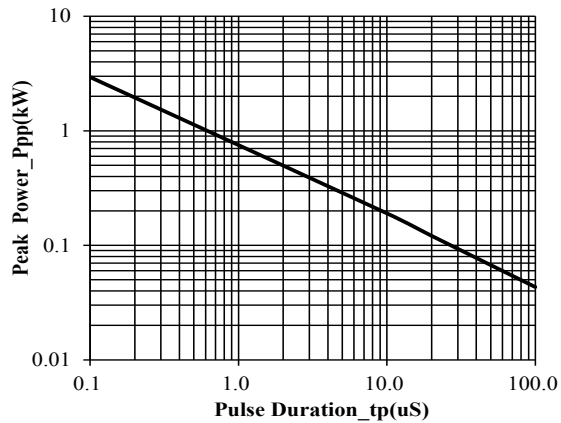


V-I characteristics for a Bi-directional TVS

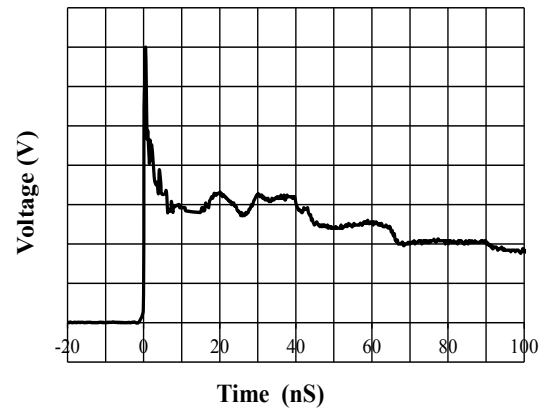
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VRWM	Reverse Working Peak Voltage				5.0	V
VBR	Reverse Breakdown Voltage	$I_T = 1\text{mA}$	6.0	7.0	8.5	V
IR	Reverse Leakage Current	$V_{RWM} = 5.0\text{V}$			1	μA
VC1	Clamping Voltage	$I_{PP} = 1\text{A}$ (8/20 μs)			8	V
VC2	Clamping Voltage	$I_{PP} = 7\text{A}$ (8/20 μs)		11	16	V
Ipp	Peak Pulse Current	$t_p = 8/20\mu\text{s}$			7	A
CJ	Capacitance	$V_R = 0\text{V}$, $f = 1\text{MHz}$		15	20	pF

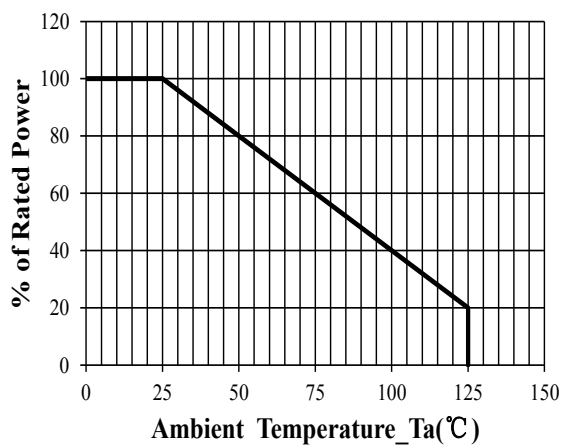
RATING AND CHARACTERISTIC CURVES (CESDBLC5V0D5)



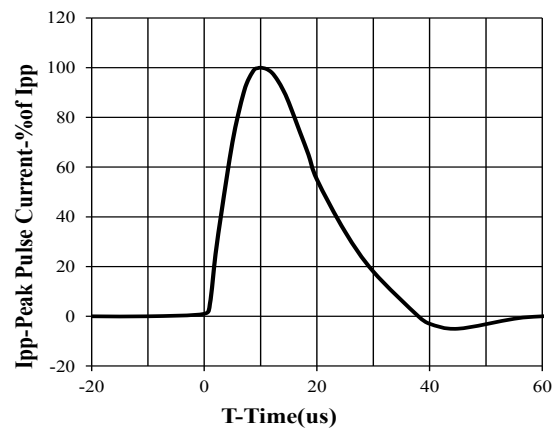
Peak Pulse Power vs. Pulse Time



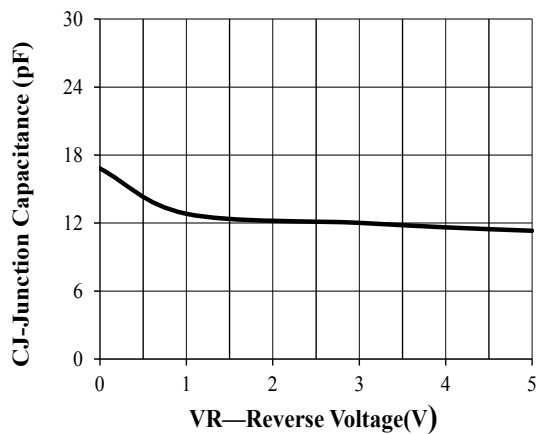
IEC61000-4-2 Pulse Waveform



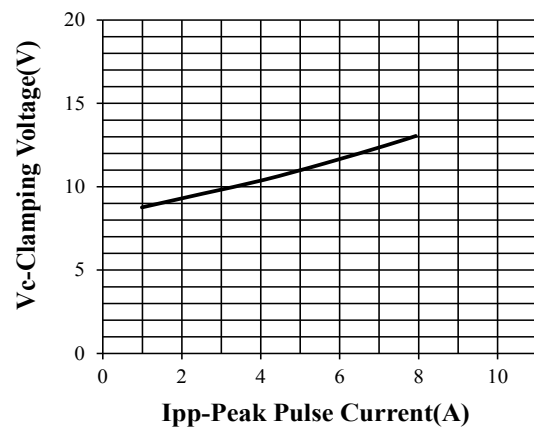
Power Derating Curve



8 X 20us Pulse Waveform



Junction Capacitance vs. Reverse Voltage



Clamping Voltage vs. Peak Pulse Current